

Surface Mount Schottky Rectifiers

Features

- Low profile package
- Ideal for automated placement
- Ultrafast reverse recovery time
- Low power losses, high efficiency
- Low forward voltage drop
- High surge capability
- High temperature soldering:
 260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/1 and WEEE 2002/96/EC



 Case: JEDEC MSMA molded plastic body over glass passivated chip

 Terminals: Solder plated, solderable per J-STD-002B and JESD22-B102D

• Polarity: Laser band denotes cathode end





Major Ratings and Characteristics

I _{F(AV)}	1.0 A
V _{RRM}	20 V to 100 V
I _{FSM}	30 A
V _F	0.50V,0.55V,0.70V,0.85V
T _j max.	125 °C

Maximum Ratings & Thermal Characteristics

(T_A = 25 °C unless otherwise noted)

Items	Symbol	MASK 12	MASK 13	MASK 14	MASK 15	MASK 16	MASK 18	MASK 110	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	V
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	V
Maximum average forward rectified current	I _{F(AV)}	1.0						Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30						Α	
Voltage rate of change (rated V _R)	dv/dt	10000						V/µs	
Thermal resistance from junction to lead ⁽¹⁾	$R_{\theta JL}$	35						°C/W	
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +125						$^{\circ}$	

Note 1: Mounted on P.C.B. with 0.2 x 0.2" (5.0 x 5.0mm) copper pad areas.

Electrical Characteristics (T_A = 25 °C unless otherwise noted)

Items	Test conditions		Symbol	MASK 12	MASK13~ MASK14	MASK15~ MASK16	MASK18~ MASK110	UNIT
Instantaneous forward voltage	I _F =1.0A ⁽²⁾		V_{F}	0.50	0.55	0.70	0.85	V
Reverse current	V _R =V _{DC}	T _A =25℃ T _A =100℃	I _R	0.5 10				mA

Note 2: Pulse test:300µs pulse width,1% duty cycle.



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Characteristic Curves (T_A=25 ℃ unless otherwise noted)

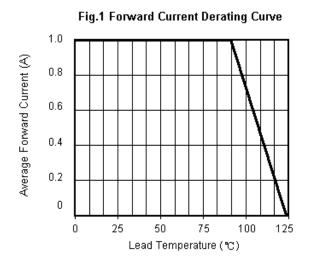


Fig.3 Typical Instantaneous Forward Characteristics

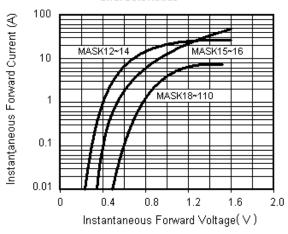


Fig.5 Typical Junction Capacitance

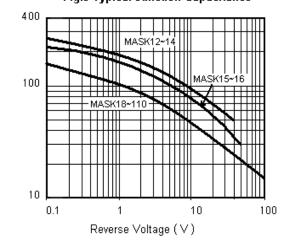


Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

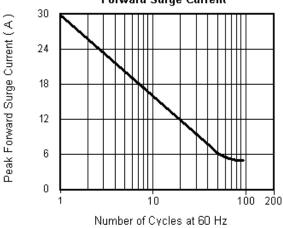
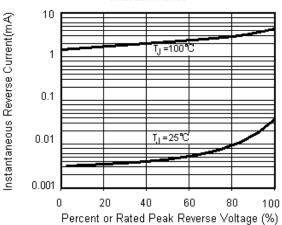


Fig.4 Typical Reverse Leakage Characteristics



Junction Capacitance (pF)



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Package Outline

MSMA Cathode Band 1.60(0.063) 2.80(0.110) 2.40(0.094) 1.20(0.047) 3.70(0.146) 3.30(0.130) 1.40(0.055) 1.20(0.047) L 0.25(0.010) 0.15(0.006) 0.10(0.004)max 1.20(0.047) 0.60(0.024) 4.70(0.185) 4.30(0.169)

Dimentsions in millimeters and (inches)

Notice

- Product is intended for use in general electronics applications.
- Product should be worked less than the ratings; if exceeded, may cause permanent damage.or introduce latent failure mechanisms.
- The absolute maximum ratings are rated values and must not be exceeded during operation. The following are the general derating methods you design a circuit with a device.
 - $I_{\text{F(AV)}}\!:\!\text{We recommend that the worst case current be no greater than 80%}$.
 - I_{FSM}: This rating specifies the non-repetitive peak current. This is only applied for an abnormal operation, which the general during the lifespan of the device.
 - T_J: Derate this rating when using a device in order to ensure high reliability. We recommend that the device be used at a T_J of below 125°C.
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- Rising-sun Technology does not assure any liability arising out of the applications or any product described in this specification.
- Rising-sun Technology advises customers to obtain the latest version of the device information before placing orders to verify that the
 required information is current.